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Absolute Maximum Ratings

Parameter	Symbol	Values	Unit
Collector Base Voltage	V _{CBO}	60	
Collector Emitter Voltage	V _{CEO}	00	V
Emitter Base Voltage	V _{EBO}	5	
Collector Current	Ι _c	4	٨
Base Current	I _B	0.1	A
Total Power Dissipation at T _a = 25°C Derate above 25°C	р	1.25 10	W mW/°C
Total Power Dissipation at T _C = 25°C Derate above 25°C	۳ _D	40 0.32	W W/°C
Operating and Storage Junction Temperature Range	T _j , T _{stg}	-55 to +150	°C
Thermal Resistance			
Junction to Case	R _{th (i-c)}	3.13	°C/M
Junction to Ambient in Free Air	R _{th (i-a)}	100	0/11

Electrical Characteristics ($T_c = 25^{\circ}C$ unless specified otherwise)

Symbol	Test Condition	Min.	Max.	Unit
V _{CEO} *	I _C = 50mA, I _B = 0	60	-	V
I _{CEO} I _{CBO}	V_{CE} = Half Rated V_{CEO} , I_B = 0 V_{CB} = Rated V_{CBO} , I_E = 0	_	500 0.2	μA mA
I _{сво}	V_{CB} = Rated V_{CBO} , I_{E} = 0 T_{C} = 100°C		2	mA
I _{EBO}	V _{EB} = 5V, I _C = 0	-	2	mA
V _{CE (sat)} *	I _C = 1.5A, I _B = 6mA I _C = 2A, I _B = 8mA	-	2.5 2.8	M
V _{EB (on)} *	$I_{C} = 1.5A, V_{CE} = 3V$ $I_{C} = 2A, V_{CE} = 3V$	-	2.5 2.5	V
h _{FE} *	$I_{C} = 1.5A, V_{CE} = 3V$ $I_{C} = 2A, V_{CE} = 3V$	750 750	-	-
h _{fe}	I _C = 1.5A, V _{CE} = 3V f = 1MHz	1	-	-
	Symbol V _{CEO} * I _{CEO} I _{CBO} I _{CBO} V _{CE} (sat)* V _{EB} (on)* h _{FE} * h _{fe}	$\begin{array}{ c c c c } \hline Symbol & Test Condition \\ \hline V_{CEO}^{*} & I_{C} = 50 mA, I_{B} = 0 \\ \hline V_{CE} = Half Rated V_{CEO}, I_{B} = 0 \\ \hline V_{CB} = Rated V_{CBO}, I_{E} = 0 \\ \hline V_{CB} = Rated V_{CBO}, I_{E} = 0 \\ \hline V_{CB} = Rated V_{CBO}, I_{E} = 0 \\ \hline V_{CB} = 100^{\circ}C \\ \hline I_{EBO} & V_{EB} = 5V, I_{C} = 0 \\ \hline V_{CE (sat)}^{*} & I_{C} = 1.5A, I_{B} = 6mA \\ \hline I_{C} = 2A, I_{B} = 8mA \\ \hline V_{EB (on)}^{*} & I_{C} = 1.5A, V_{CE} = 3V \\ \hline I_{C} = 2A, V_{CE} = 3V \\ \hline I_{C} = 2A, V_{CE} = 3V \\ \hline I_{C} = 2A, V_{CE} = 3V \\ \hline I_{C} = 1.5A, V_{CE} = 3V \\ \hline I_{C} = 1.5A $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

*Pulse Test : Pulse Width = ≤300µs, Duty Cycle = ≤2%.

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Pin Configuration:

1. Emitter

2. Collector

3. Base

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Recommended Reflow Solder Profiles

The recommended reflow solder profiles for Pb and Pb-free devices are shown below.

Figure 1 shows, the recommended solder profile for devices that have Pb-free terminal plating, and where a Pb-free solder is used.

Figure 2 shows, the recommended solder profile for devices with Pb-free terminal plating used with leaded solder, or for devices with leaded terminal plating used with a leaded solder.



Reflow profiles in Tabular Form

Profile Feature	Sn-Pb System	Pb-Free System
Average Ramp-Up Rate	~3°C/second	~3°C/second
Preheat – Temperature Range – Time	150°C ~ 170°C 60-180 seconds	150°C ~ 200°C 60-180 seconds
Time maintained above: – Temperature – Time	200°C 30-50 seconds	217°C 60-150 seconds
Peak Temperature	235°C	260°C max.
Time within +0 -5°C of actual Peak	10 seconds	40 seconds
Ramp-Down Rate	3°C/second max.	6°C/second max.

Recommended Wave Solder Profiles





The recommended solder profile for devices with Pb-free terminal plating where a Pb-free solder is used.

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Wave Profile in Tabular Form

Profile Features	Sn-Pb System	Pb-Free System
Average Ramp-Up Rate	~200°C/Second	~200°C/Second
Heating rate during Preheat	Typical 1-2, Max. 4°C/Sec.	Typical 1-2, Max. 4°C/Sec.
Final Preheat Temperature	Within 125°C of solder Temp.	Within 125°C of solder Temp.
Peak Temperature	235°C	260°C
Time within +0 -5°C of actual Peak	10 Seconds	10 Seconds
Ramp-Down Rate	5°C/Second Max.	5°C/Second Max.

Recommended Manual Soldering

3 Sec at 350°C or 10 Sec at 260°C for Sn/Pb System





Pin Configuration:

- 1. Emitter
- 2. Collector
- 3. Base

Dimensions	Min.	Max.
A	7.4	7.8
В	10.5	10.8
С	2.4	2.7
D	0.7	0.9
E	2.25 (Typical)	
F	0.49	0.75
G	4.5 (Typical)	
L	15.7 (Typical)	
М	1.27 (Typical)	
N	3.75 (Typical)	
Р	3	3.2
S	2.5 (Typical)	

Part Number Table

Description	Part Number	
Darlington Transistor, TO-126	BD678	

Dimensions : Millimetres

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